

INCHANGE SEMICONDUCTOR

isc Silicon PNP Power Transistor

2SB1548A

DESCRIPTION

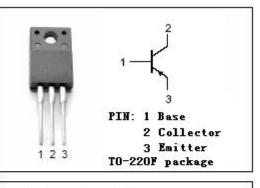
- Collector-Emitter Breakdown Voltage-
- : V_{(BR)CEO}= -80V(Min)
- Collector Power Dissipation-: P_C = 25 W@ T_C = 25 °C
- Low Collector Saturation Voltage
- Complement to Type 2SD2374A
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

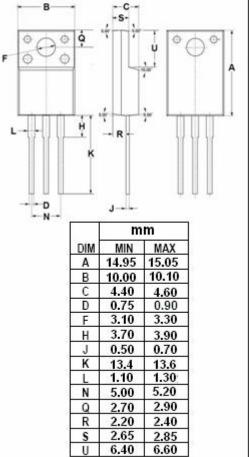
APPLICATIONS

• Designed for power amplifications.

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

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SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	-80	V	
Vceo	Collector-Emitter Voltage	-80	V	
V _{EBO}	Emitter-Base Voltage	-5	V	
lc	Collector Current-Continuous	-3	А	
I _{CM}	Collector Current-Peak	-5	А	
Pc	Collector Power Dissipation @Ta=25℃	2	W	
	Collector Power Dissipation @T _c =25°C	25		
TJ	Junction Temperature	150 °C		
Tstg	Storage Temperature	-55~150	°C	





1



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ELECTRICAL CHARACTERISTICS

Tj=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -3Α; I _B = -0.375Α			-1.2	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = -3A ; V _{CE} = -4V			-1.8	V
I _{CES}	Collector Cutoff Current	V _{CE} = -80V ; V _{BE} = 0			-200	μA
I _{CEO}	Collector Cutoff Current	V _{CE} = -60V ; I _B = 0			-300	μA
I _{EBO}	Emitter Cutoff Current	V _{EB} = -5V; I _C = 0			-1	mA
h _{FE-1}	DC Current Gain	I _C = -1A ; V _{CE} = -4V	70		250	
h _{FE-2}	DC Current Gain	Ic= -3A ; Vce= -4V	10			
fT	Current-Gain—Bandwidth Product	I _C = -0.5A;V _{CE} = -10V; f _{test} = 10MHz		30		MHz

Switching Times

t _{on}	Turn-on Time		0.5	μs
t _{stg}	Storage Time	I _C = -1A, I _{B1} = -I _{B2} = -0.1A,	1.2	μs
tf	Fall Time		0.3	μs

2

♦ h_{FE-1} Classifications

Q	Р
70-150	120-250



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3

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